International **TOR** Rectifier

Hyperfast Rectifier

Features

diodes.

- · Hyperfastfast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current

Description/Applications

and reliability characteristics.

• 175°C Operating Junction Temperature

Hyperfast recover time, and soft recovery.

dissipation in the switching element and snubbers.

 $t_{rr} = 40$ ns $I_{F(AV)} = 30$ Amp $V_R = 600V$

30EPH06

Absolute Maximum Ratings

Parameters	Мах	Units
Peak Repetitive Peak Reverse Voltage	600	V
Average Rectified Forward Current	30	A
Non Repetitive Peak Surge Current	325	
Peak Repetitive Forward Current	70	
Operating Junction and Storage Temperatures	- 65 to 175	°C
	Peak Repetitive Peak Reverse Voltage Average Rectified Forward Current Non Repetitive Peak Surge Current Peak Repetitive Forward Current	Peak Repetitive Peak Reverse Voltage600Average Rectified Forward Current30Non Repetitive Peak Surge Current325Peak Repetitive Forward Current70

State of the art Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop,

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness

These devices are intended for use in PFC Boost stage in the AC-DC section of SMPS, inverters or as freewheeling

The IR extremely optimized stored charge and low recovery current minimize the switching losses and reduce over



Electrical Characteristics @ $T_J = 25^{\circ}C$ (unless otherwise specified)

	Parameters	Min	Тур	Max	Units	Test Conditions
V _{BR} , V _r	Breakdown Voltage, Blocking Voltage	600	-	-	V	I _R = 100μA
VF	Forward Voltage	-	-	2.1	V	I _F = 30A, T _J = 25°C
		-	-	1.7	V	I _F = 30A, T _J = 150°C
I _R	Reverse Leakage Current	-	-	250	μA	V _R = V _R Rated
		-	-	1.0	mA	$T_J = 150^{\circ}C, V_R = V_R Rated$
CT	Junction Capacitance	-	-	-	pF	V _R = 600V
Ls	Series Inductance	-	-	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameters	Min	Тур	Max	Units	Test Conditions		
t _{rr}	Reverse Recovery Time	-	-	40	ns	I_F = 1.0A, di _F /dt = 50A/µs, V _R = 30V		
		-	-	-		$I_F = 30A, di_F/dt = 2$	= 200A/µs, V _R = 200V	
		-	-	-		$T_J = 25^{\circ}C$	I _F = 30A	
			-	-		T _J = 125°C	V _R = 200V di _F /dt = 200A/µs	
I _{RRM}	Peak Recovery Current	-	-	-	А	$T_J = 25^{\circ}C$	uif7ut – 2007vµs	
		-	-	-		T _J = 125°C		
Qrr	Reverse Recovery Charge	-	-	100	nC	T _J = 25°C		
		-	-	-		T _J = 125°C		

Thermal - Mechanical Characteristics

	Parameters		Min	Тур	Мах	Units
TJ	Max. Junction Temperature Range		-	-	- 65 to 175	°C
T _{Stg}	Max. Storage Temperature Range		-	-	- 65 to 175	
R _{thJC}	Thermal Resistance, Junction to Case	Per Leg	-	-	1.2	°C/W
R _{thJA} ^①	Thermal Resistance, Junction to Ambient	Per Leg	-	-	-	
R_{thCS}^{2}	Thermal Resistance, Case to Heatsink		-	-	-	
Wt	Weight		-	2.0	-	g
			-	0.07	-	(oz)
	Mounting Torque		6.0	-	12	Kg-cm
			5.0	-	10	lbf.in

Typical Socket Mount
Mounting Surface, Flat, Smooth and Greased

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